Claims

We claim:

1. An electronic structure, comprising: 1 2 a metallic plate; a mineral layer bonded to the metallic plate; and 3 an adhesion promoter layer bonded to the mineral layer. 2. The structure of claim 1, wherein the mineral layer includes a mineral selected from the group consisting of silicon dioxide, silicon nitride, and silicon carbide. 3. The structure of claim 1, wherein the mineral layer has a thickness between about 50 angstroms and about 2000 angstroms. 4. The structure of claim 1, wherein the metallic plate includes a metallic substance selected from 1 the group consisting of stainless steel, aluminum, titanium, copper, copper coated with nickel, 2 3 and copper coated with chrome.

5. The structure of claim 1, wherein the adhesion promoter layer includes an adhesion promoter selected from the group consisting of a silane, a titanate, a zirconate, and an aluminate.

EN9-98-117

- 6. The structure of claim 1, wherein the adhesion promoter layer includes a silane selected from 1
- the group consisting of 3-glycidoxypropyltrimethoxysilane, 3-glycidoxypropyltriethoxysilane, 3-2
- (2-aminoethyl)propyltrimethoxysilane, and 3-(2-aminoethyl)propyltriethoxysilane. 3
- 7. The structure of claim 1, further comprising: 1
- an electronic carrier; 2
- an electronic assembly coupled to the electronic carrier; and 3
- an adhesive structure bonded to the adhesion promoter layer, wherein the adhesive 4 structure adhesively couples the metallic plate to the electronic assembly, and wherein the 5 📮 adhesive structure adhesively couples the metallic plate to the electronic carrier.
 - 8. The structure of claim 7, wherein the adhesive structure includes a structural epoxy adhesive.
 - 9. The structure of claim 7, wherein a coefficient of thermal expansion (CTE) of the metallic plate exceeds a CTE of the electronic assembly.

10. A method for forming an electronic structure, comprising: providing a metallic plate; forming a mineral layer on the metallic plate; and forming an adhesion promoter layer on the mineral layer.

- 11. The method of claim 10, wherein the step of forming a mineral layer includes selecting a mineral from the group consisting of silicon dioxide, silicon nitride, and silicon carbide. 2
- 12. The method of claim 10, wherein the step of forming a mineral layer includes forming a mineral layer having a thickness between about 50 angstroms and about 2000 angstroms.
 - 13. The method of claim 10, wherein the step of forming a mineral layer includes sputtering a mineral layer on the clean surface of the metallic plate.
- 14. The method of claim 10, wherein the providing step includes selecting a metallic substance 1
- from the group consisting of stainless steel, aluminum, titanium, copper, copper coated with 2
- 3 nickel, and copper coated with chrome.
- 15. The method of claim 10, wherein the step of forming an adhesion promoter layer includes 1
- selecting an adhesion promoter from the group consisting of a silane, a titanate, a zirconate, and 2
- 3 an aluminate.

- 1 0, wherein the step of forming an adhesion promoter layer includes
- 2 selecting a silane from the group consisting of 3-glycidoxypropyltrimethoxysilane, 3-
- 3 glycidoxypropyltriethoxyslane, 3-(2-aminoethyl)propyltrimethoxysilane, and 3-(2-
- 4 aminoethyl)propyltrmethoxysilane.

Sub 1 -

17. The method of claim 10, further comprising:

providing an electronic assembly;

providing an adhesive material;

coupling the metallic plate to the electronic assembly by interfacing the adhesive material between the adhesion promoter layer and the electronic assembly;

providing an electronic carrier;

coupling the electronic assembly to the electronic carrier; and

coupling the metallic plate to the electronic carrier by interfacing the adhesive material between the adhesion promoter layer and the electronic carrier.

- 1 18. The method of claim 17, wherein the step of providing an adhesive material includes
- 2 providing a structural epoxy adhesive.
- 1 19. The method of claim 17, wherein the step of providing a metallic plate includes providing a
- 2 metallic plate having a coefficient of thermal expansion (CTE) that exceeds a CTE of the
- 3 electronic assembly.

Add A 17